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				Application Number	10/572,196		
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Filing Date	September 21, 2006 Herz et al.		
				First Named Inventor			
				Art Unit	2811		
				Examiner Name	Hung K. Vu		
Sheet	1	of	1	Attorney Docket Number	1031-03		

		NON PATENT LITERATURE DOCUMENTS		
Examiner Initials*	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		
	1	WESTE et al., CMOS Processing Technology, Principles of CMOS VLSI Design, A Systems Perspective, 1985, pp. 64-67, Addison-Wesley Publishing Company.		
	2	WESTE et al., CMOS Processing Technology, Principles of CMOS VLSI Design, A Systems Perspective, 1993, pp. 109-113, Addison-Wesley Publishing Company.		

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